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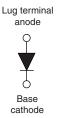
RoHS

COMPLIANT

High Performance Schottky Rectifier, 120 A



www.vishay.com



HAL	F-PAK	(D-67)

PRODUCT SUMMARY				
I _{F(AV)}	120 A			
V _R	45 V			
Package	HALF-PAK (D-67)			
Circuit	Single diode			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-120NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNIT					
I _{F(AV)}	Rectangular waveform	120	A				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	26 000	A				
V _F	120 A _{pk} , T _J = 125 °C	0.62	V				
ŢJ	Range	-55 to +150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-120NQ045PbF	UNITS			
Maximum DC reverse voltage	V _R	45	N/			
Maximum working peak reverse voltage	V _{RWM}	– 45 V				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 105 °C, rectangular waveform		120		
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	26 000	А	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	1550		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 13 A, L = 1 mH		81	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		13	А	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		120 A	T _ 25 °C	0.63	v	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	240 A	— T _J = 25 °C	0.86		
See fig. 1	VFM (")	120 A		0.62		
		240 A	$1_{\rm J} = 125$ C	0.81		
Maximum reverse leakage current	. (1)	T _J = 25 °C		10	mA	
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	500		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		5200	pF	
Typical series inductance	L _S	From top of terminal hole to mounting plane		7.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

⁽¹⁾ Pulse width < 500 μ s

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage tempe	erature range	T _J , T _{Stg}		-55 to 150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	0.38	°C/W
Typical thermal resistance, case to h	eatsink	R _{thCS}	Mounting surface, smooth and greased	0.05	
Approximate weight				30	g
				1.06	oz.
Mounting torque	minimum			3 (26.5)	
Mounting torque	maximum		Non-lubricated threads	4 (35.4)	N · m (lbf · in)
Terminal terraua	minimum		Non-lubricated trireaus	3.4 (30)	
Terminal torque	maximum			5 (44.2)	1
Case style				HALF-PAP	K module

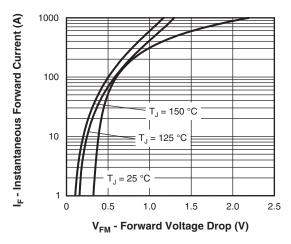
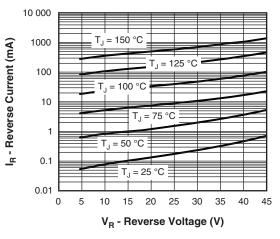
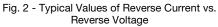


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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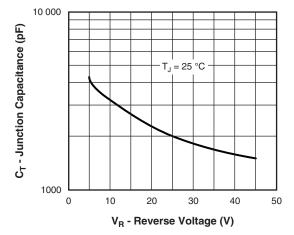


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

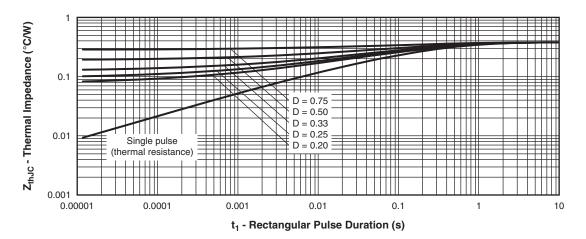
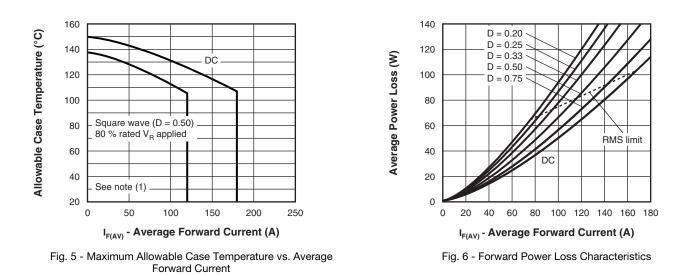


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



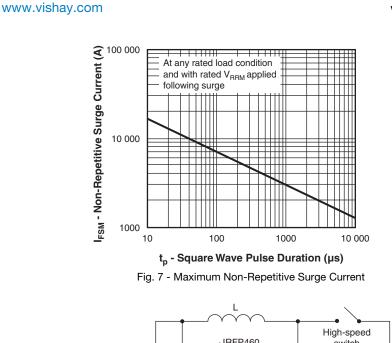
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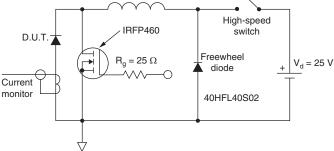
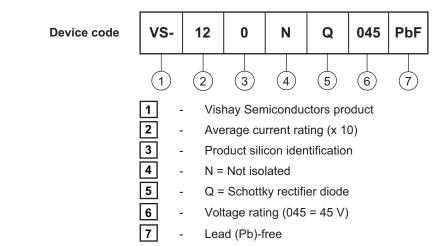


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = Rated V_R$

ORDERING INFORMATION TABLE



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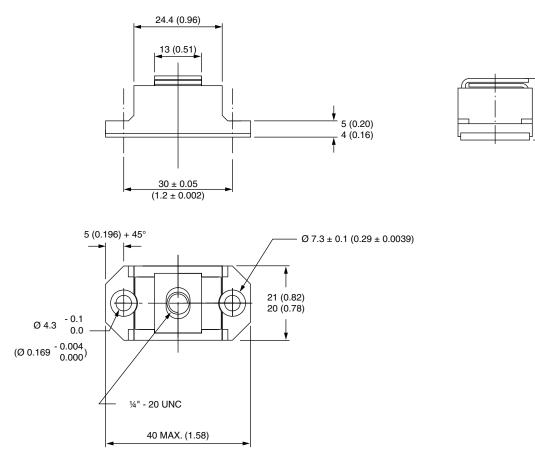
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17.5 (0.69) 16.5 (0.65)



DIMENSIONS in millimeters (inches)

SHAY





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